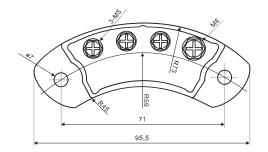
### DONGGUAN NANJING ELECTRONICS LTD.,

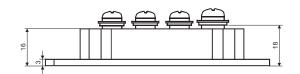
## **Nell High Power Products**

## MXG50/MXY50 Series

# Arc Type Rectifier Module, 50A







All dimensions in millimeters

### **FEATURES**

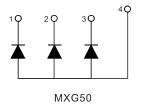
- Typical IR less than 2.0 μA
- High surge current capability
- Low thermal resistance
- Compliant to RoHS
- Isolation voltage up to 2500V

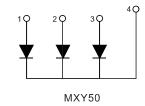
### **TYPICAL APPLICATIONS**

General purpose use in AC/DC bridge full wave rectification for big power generator, field supply for DC motor, industrial automation applications.

#### **ADVANTAGE**

- International standard package Epoxy meets UL 94 V-O flammability rating
- Small volume, light weight
- Small thermal resistance
- High heat-conduction rate
- Low temperature rise
- Weight: 120g (4.2 ozs)





PRIMARY CHARACTERRISTICS				
I <sub>F(AV)</sub>	50A			
V <sub>RRM</sub>	800V to 1600V			
I <sub>FSM</sub>	450A			
I <sub>R</sub>	5 μΑ			
V <sub>F</sub>	1.30V			
T <sub>J max</sub> .	150°C			

# MXG50/MXY50 Series

# **Nell High Power Products**

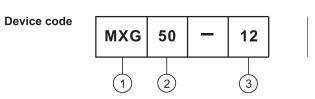
MAJOR RATINGS AND CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	SYMBOL		LINIT			
		08	12	16	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	800	1200	1600	V	
Peak reverse non-repetitive voltage	V <sub>RSM</sub>	900	1300	1700	V	
Maximum DC blocking voltage	V <sub>DC</sub>	800	1200	1600	V	
Maximum average forward rectified output current	I <sub>F(AV)</sub>	50			А	
Peak forward surge current single sine-wave superimposed on rated load	I <sub>FSM</sub>	450			А	
Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms) for fusing	l <sup>2</sup> t	1012			A <sup>2</sup> s	
RMS isolation voltage from case to leads	V <sub>ISO</sub>	2500			V	
Operating junction storage temperature range	TJ	-40 to 150			°C	
Storage temperature range	T <sub>stg</sub>	-40 to 125			°C	

ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	TEST	SYMBOL		UNIT		
PARAIMETER	CONDITIONS		08	12	<b>1</b> 6	ONII
Maximum instantaneous forward drop per diode	I <sub>F</sub> = 157A	V <sub>F</sub>	1.30			V
Maximum reverse DC current at rated DC blocking	T <sub>A</sub> = 25°C	ls.	5			
voltage per diod	T <sub>A</sub> = 150°C	- I <sub>R</sub>	3			

THERMAL AND MECHANICAC (T <sub>A</sub> = 25°C unless otherwise noted)							
PARAMETER TEST	TEST CONDITIONS	SYMBOL			LIMIT		
	TEST CONDITIONS		08	12	16	UNIT	
Typical thermal resistance junction to case	Single-side heat dissipation, sine half wave	R <sub>θJC</sub> <sup>(1)</sup>	1.0			°C/W	
Mounting torque <sup>(2)</sup>	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.		2.0 to 2.5			Nm	
Approximate weight				120		g	

#### Notes

- (1) With heatsink, single side heat dissipation, half sine wave.
- (2) M5 & M6 screws.



- MXG = for common anode
  MXY = for common cathode
- I<sub>F(AV)</sub> rating: "50" for 50A
  Voltage code: code x 100 = V<sub>RRM</sub>